General Description

The MAX1171 analog-to-digital converter (ADC) is a 12-bit monolithic ADC capable of sample rates greater than 20Msps. An on-board input buffer and track/hold function ensure excellent dynamic performance without the need for external components. A 5pF input capacitance minimizes development problems.

Logic inputs and outputs are TTL compatible. An overrange output signal is provided to indicate overflow conditions. Output data format is straight binary. Power dissipation is a very low 1.1W with power-supply voltages of +5.0V and -5.2V. The MAX1171 also provides a wide input voltage range of ±2.0V.

The MAX1171 is available in a 32-lead ceramic sidebrazed package and a 44-lead surface-mount CERQUAD package.

Features

- ♦ Monolithic, 12-Bit, 20Msps Converter
- ♦ On-Chip Track/Hold
- ♦ ±2.0V Analog Input Range
- ♦ 66dB SNR at 1MHz Input
- ♦ Low Power: 1.1W
- ♦ 5pF Input Capacitance
- **♦ TTL-Compatible Outputs**

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX1171CDJ	0°C to +70°C	32 Ceramic SB
MAX1171CBH	0°C to +70°C	44 CERQUAD

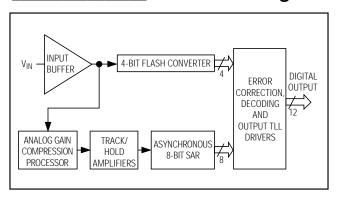
Applications

Radar Receivers Professional Video Instrumentation **Imaging**

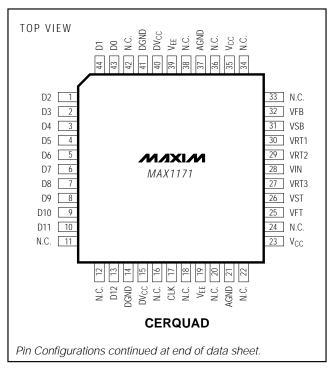
Digital Communications

Digital Spectrum Analyzers

Functional Diagram



Pin Configurations



NIXIN

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ABSOLUTE MAXIMUM RATINGS

V _C C	+6V
VEE	6V
Analog Input	$\dots V_{FB} \le V_{IN} \le V_{FT}$
VFB, VFT	3.0V, +3.0V
Reference Ladder Current	12mA
CLK IN	Vcc

Digital Outputs	0mA to -30mA
Operating Temperature Range	0°C to +70°C
Junction Temperature (Tj)	+175°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(VCC = ± 5.0 V, VEE = ± 5.0 V, DVCC = ± 5.0 V, VIN = ± 2.0 V, VSB = ± 2.0 V, VST = ± 2.0 V, fCLK = \pm

PARAMETER	CONDITIONS	TEST LEVEL	MIN	TYP	MAX	UNITS
Resolution			12			Bits
DC ACCURACY ($T_A = +25^{\circ}C$)						•
Integral Nonlinearity	± full scale	IV		±2.0		LSB
Differential Nonlinearity	250kHz sample rate	IV		±0.8		LSB
No Missing Codes		1		Guaranteed		
ANALOG INPUT						1
Input Voltage Range		VI		±2.0		V
Input Bias Current	TA = +25°C	I		30	60	μΑ
Input Resistance	$V_{IN} = 0V$, $T_A = +25$ °C	I	100	300		kΩ
Input Capacitance		V		5		pF
Input Bandwidth	3dB small signal	V		120		MHz
Positive Full-Scale Error		V		±5.0		LSB
Negative Full-Scale Error		V		±5.0		LSB
REFERENCE INPUT						1
Reference Ladder Resistance		VI	500	800		Ω
Reference Ladder Tempco		V		0.8		Ω/°C
TIMING CHARACTERISTICS						•
Maximum Conversion Rate		VI	20			MHz
Overvoltage Recovery Time		V		20		ns
Pipeline Delay (Latency)		VI			1	Clock Cycle
Output Delay	$T_A = +25^{\circ}C$	V		14	18	ns
Aperture Delay Time	T _A = +25°C	V		1		ns
Aperture Jitter Time	T _A = +25°C	V		5		ps-RMS

ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = +5.0V, V_{EE} = -5.2V, DV_{CC} = +5.0V, V_{IN} = ±2.0V, V_{SB} = -2.0V, V_{ST} = +2.0V, f_{CLK} = 20MHz, 50% clock duty cycle, T_A = T_{MIN} to T_{MAX} , unless otherwise noted.)

PARAMETER	CONDITIONS		TEST LEVEL	MIN	TYP	MAX	UNITS
DYNAMIC PERFORMANCE	1		<u>'</u>				
	$f_{IN} = 500kHz$ $f_{IN} = 1MHz$ $f_{IN} = 3.58MHz$				10.2		
Effective Number of Bits					10.0		Bits
					9.5		1
	f _{IN} = 500kHz	T _A = +25°C	I	64	67		
	IIM = 200KHZ	$T_A = T_{MIN}$ to T_{MAX}	IV	58	61		
Signal-to-Noise Ratio	f _{IN} = 1MHz	$T_A = +25^{\circ}C$	_	64	66		dB
(without Harmonics)	IIIV - IIVII IZ	$T_A = T_{MIN}$ to T_{MAX}	IV	58	60		GD.
	f _{IN} = 3.58MHz	$T_A = +25^{\circ}C$	_	62	64		
	1 \(- 3.36 \(\) 12	$T_A = T_{MIN}$ to T_{MAX}	IV	58	60		
	f _{IN} = 500kHz	$T_A = +25^{\circ}C$		63	66		
	1 \(= 300K112	$T_A = T_{MIN}$ to T_{MAX}	IV	59	62		
Harmonic Distortion	f _{IN} = 1MHz	T _A = +25°C	I	63	65		dB
Harmonic Distortion	IIIV - IIVII IZ	$T_A = T_{MIN}$ to T_{MAX}	IV	59	61		db db
	f _{IN} = 3.58MHz	T _A = +25°C	I	59	61		
	1 \(- 3.36 \(\) 12	$T_A = T_{MIN}$ to T_{MAX}	IV	57	59		
	f _{IN} = 500kHz	T _A = +25°C	I	60	63		dB
	1 \(- 300K112	$T_A = T_{MIN}$ to T_{MAX}	IV	55	58		
Signal-to-Noise and Distortion	f _{IN} = 1MHz	T _A = +25°C	I	60	62		
Signal-to-Noise and Distortion		$T_A = T_{MIN}$ to T_{MAX}	IV	55	57		
	f _{IN} = 3.58MHz	$T_A = +25^{\circ}C$	I	57	59		
		$T_A = T_{MIN}$ to T_{MAX}	IV	54	56		
Spurious-Free Dynamic Range	$f_{IN} = 1MHz, T_A =$	+25°C	V		74		dBc
Differential Phase	$f_{IN} = 3.58MHz$ an $T_A = +25$ °C	d 4.35MHz,	V		0.2		Degrees
Differential Gain	$f_{IN} = 3.58MHz$ an $T_A = +25$ °C	d 4.35MHz,	V		0.7		%
DIGITAL INPUTS							
Logic "1" Voltage			V	2.4		4.0	V
Logic "0" Voltage			V			0.8	V
Maximum Input Current Low	T _A = +25°C		I	0	5	20	μΑ
Maximum Input Current High	$T_A = +25^{\circ}C$		I	0	5	20	μA
Pulse Width Low (CLK)			IV	20			ns
Pulse Width High (CLK)			IV	20		300	ns
DIGITAL OUTPUTS			· · · · · · · · · · · · · · · · · · ·				•
Logic "1" Voltage	$T_A = +25^{\circ}C$		I	2.4			V
Logic "0" Voltage	T _A = +25°C		-			0.6	V

ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = +5.0V, V_{EE} = -5.2V, DV_{CC} = +5.0V, V_{IN} = ±2.0V, V_{SB} = -2.0V, V_{ST} = +2.0V, f_{CLK} = 20MHz, 50% clock duty cycle, T_A = T_{MIN} to T_{MAX} , unless otherwise noted.)

PARAMETER	CONDITIONS	TEST LEVEL	MIN	TYP	MAX	UNITS
POWER-SUPPLY REQUIREMEN	NTS					
	V _{CC}	IV	4.75	5.0	5.25	
Voltages	DV _{CC}	IV	4.75	5.0	5.25	V
	-V _{EE}	IV	-4.95	-5.2	-5.45	
	I _{CC} , T _A = +25°C	I		135	150	
Currents	DI_{CC} , $T_A = T_{MIN}$ to T_{MAX}	IV		40	55	mA
	-I _{EE} , T _A = +25°C	I		45	70	
Power Dissipation		VI		1.1	1.3	W
Power-Supply Rejection	5V ±0.25V, -5.2V ±0.25V	V		1.0		LSB

Note 1: Typical thermal impedances (unsoldered, in free air):

32 Ceramic SB: $\theta j_A = 50$ °C/W

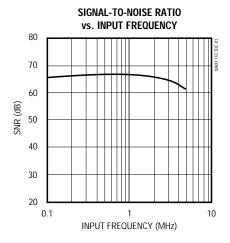
44 CERQUAD: $\theta_{jA} = 78^{\circ}$ C/W, θ_{jA} at 1m/s airflow = 58° C/W, $\theta_{jC} = 3.3^{\circ}$ C/W

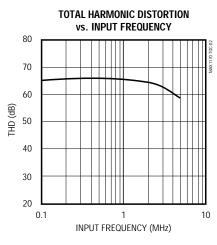
Use forced-air cooling or heatsinking to maintain $T_i \le 150$ °C.

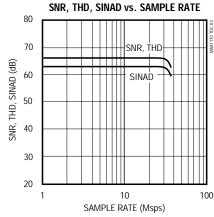
TEST LEVEL CODES	TEST LEVEL	TEST PROCEDURE
All electrical characteristics are subject to the	1	100% production tested at the specified temperature.
following conditions: All parameters having min/max specifications	II	100% production tested at $T_A = +25$ °C, and sample tested at the specified temperatures.
are guaranteed. The Test Level column indi- cates the specific device testing actually per-	III	QA sample tested only at the specified temperatures.
formed during production and Quality Assurance inspection. Any blank section in the	IV	Parameter is guaranteed (but not tested) by design and characterization data.
data column indicates that the specification is not tested at the specified condition.	V	Parameter is a typical value for information purposes only.
Unless otherwise noted, all tests are pulsed; therefore, $T_j = T_C = T_A$.	VI	100% production tested at $T_A = +25^{\circ}\text{C}$. Parameter is guaranteed over specified temperature range.

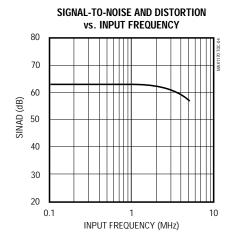
Typical Operating Characteristics

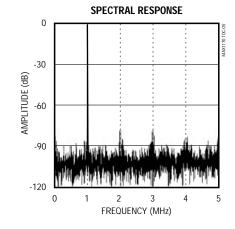
(fs = 20Msps, f_{IN} = 1MHz, T_A = +25°C, unless otherwise noted.)

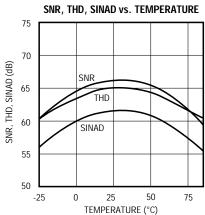












_____Pin Description

Р	IN	NAME	FUNCTION	
Ceramic SB	CERQUAD	NAME	FUNCTION	
1, 15	14, 41	DGND	Digital Ground	
2–13	43, 44, 1–10	D0-D11	TTL Outputs (D0 = LSB)	
14	13	D12	TTL Output Overrange Bit	
16, 32	15, 40	DV _{CC}	Digital +5.0V Supply (TTL Outputs)	
17	17	CLK	TLL Clock Input	
18, 31	19, 39	V _{EE}	-5.2V Supply	
19, 30	21, 37	AGND	Analog Ground	
20, 29	23, 35	V _{CC}	+5.0V Supply	
21	25	VFT	Force for Top of Reference Ladder	
22	26	VST	Sense for Top of Reference Ladder	
23	27	VRT3	Voltage Reference Tap 3	
24	28	VIN	Analog Input, 2.0V typical	
25	29	VRT2	Voltage Reference Tap 2	
26	30	VRT1	Voltage Reference Tap 1	
27	31	VSB	Sense for Bottom of Reference Ladder	
28	32	VFB	Force for Bottom of Reference Ladder	
_	11, 12, 16, 18, 20, 22, 24, 33, 34, 36, 38, 42	N.C.	No Connection	

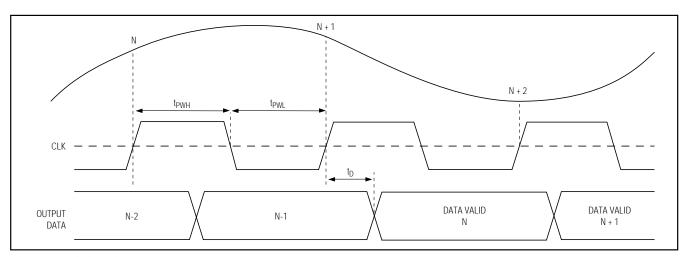


Figure 1a. Timing Diagram

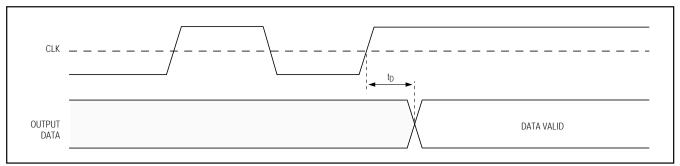


Figure 1b. Single-Event Clock

Table 1. Timing Parameters

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNITS
t _D	CLK to Data Valid Prop Delay		14	18	ns
tpWH	CLK High Pulse Width	20		300	ns
tpwL	CLK Low Pulse Width	20			ns

Detailed Description

The MAX1171 requires few external components to achieve the stated operation and performance. Figure 2 shows the typical interface requirements when using the MAX1171 in normal circuit operation. The following section provides a description of the pin functions and outlines critical performance criteria for achieving the optimal device performance.

Power Supplies and Grounding

The MAX1171 requires -5.2V and +5V analog supply voltages. The +5V supply is common to analog V_{CC} and digital DV_{CC}. A ferrite bead in series with each supply line reduces the transient noise injected into the analog V_{CC}. These beads should be connected as close to the device as possible. The connection between the beads and the MAX1171 should not be shared with any other device. Bypass each power-supply pin as close to the device as possible. Use $0.1\mu F$ for V_{EE} and V_{CC} , and $0.01\mu F$ for DV_{CC} (chip capacitors are preferred).

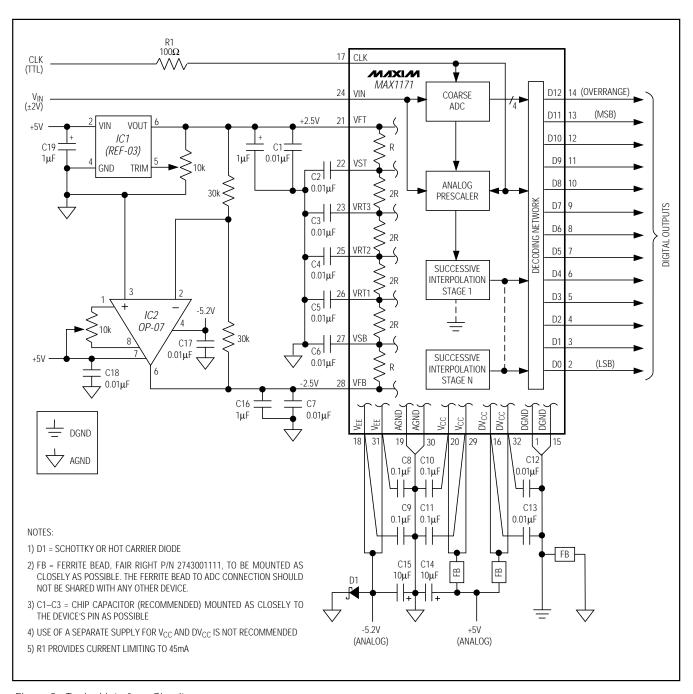


Figure 2. Typical Interface Circuit

AGND and DGND are the two grounds available on the MAX1171. These two internal grounds are isolated on the device. The use of ground planes is recommended to achieve optimum device performance. DGND is needed for the DV_{CC} return path (40mA typical) and for the return path for all digital output logic interfaces. AGND and DGND should be separated from each other and connected together only at the device through a ferrite bead.

A Schottky or hot carrier diode connected between AGND and V_{EE} is required. The use of separate power supplies between V_{CC} and DV_{CC} is not recommended due to potential power-supply sequencing latchup conditions. Use of the recommended interface circuit shown in Figure 2 will provide optimum device performance for the MAX1171.

Voltage Reference

The MAX1171 requires the use of two voltage references: V_{FT} and V_{FB} . V_{FT} is the force for the top of the voltage reference ladder (+2.5V typical), V_{FB} (-2.5V typical) is the force for the bottom of the voltage reference ladder. Both voltages are applied across an internal reference ladder resistance of 800Ω . The +2.5V voltage source for reference V_{FT} must be current limited to 20mA maximum if a different driving circuit is used in place of the recommended reference circuit shown in Figures 2 and 3.

In addition, there are five reference ladder taps (VST, VRT1, VRT2, VRT3, and VSB). VST is the sense for the top of the reference ladder (+2.0V), VRT2 is the midpoint of the ladder (0.0V typical), and VSB is the sense for the bottom of the reference ladder (-2.0V). VR_{T1} and VR_{T3} are quarter-point ladder taps (+1.0V and -1.0V typical, respectively). The voltages seen at V_{ST} and VSB are the true full-scale input voltages of the device when VFT and VFB are driven to the recommended voltages (+2.5V and -2.5V typical, respectively). VST and VSB can be used to monitor the actual full-scale input voltage of the device. VR_{T1}, VR_{T2}, and VR_{T3} should not be driven to the expected ideal values, as is commonly done with standard flash converters. A decoupling capacitor of 0.01µF connected to AGND from each tap is recommended to minimize high-frequency noise injection.

The analog input range will scale proportionally with respect to the reference voltage if a different input

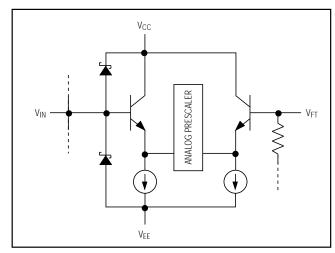


Figure 3. Analog Equivalent Input Circuit

range is required. The maximum scaling factor for device operation is $\pm 20\%$ of the recommended reference voltages of VFT and VFB. However, because the MAX1171 is laser trimmed to optimize performance with $\pm 2.5 \text{V}$ references, its accuracy will degrade if operated beyond a $\pm 2\%$ range.

An example of a recommended reference driver circuit is shown in Figure 2. IC1 is REF-03, the +2.5V reference with a tolerance of 0.6% or ± 0.015 V. The $10k\Omega$ potentiometer supports an adjustable range of 150mV. IC2 is recommended to be an OP-07 or equivalent device. R2 and R3 must be matched to within 0.1% with good TC tracking to maintain a 0.3LSB matching between VFT and VFB. If 0.1% matching is not met, then potentiometer R4 can be used to adjust the VFB voltage to the desired level. Adjust R1 and R4 such that VST and VSB are exactly +2.0V and -2.0V, respectively.

The following errors are defined:

+FS error = top of ladder offset voltage = Δ (+FS - V_{ST}) -FS error = bottom of ladder offset voltage = Δ (-FS - V_{SB})

Where the +FS (full scale) input voltage is defined as the output 1LSB above the transition of 1–10 and 1–11, and the -FS input voltage is defined as the output 1LSB below the transition of 0–00 and 0–01.

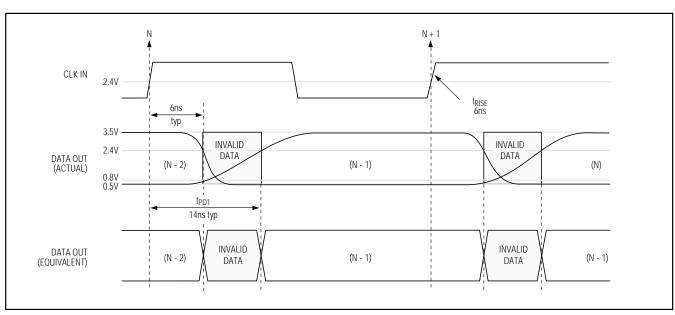


Figure 4. Digital Output Characteristics

Analog Input

 V_{IN} is the analog input. The full-scale input range will be 80% of the reference voltage or $\pm 2V$ with $V_{FB} = -2.5V$ and $V_{FT} = +2.5V$.

The drive requirements for the analog inputs are minimal compared to those of conventional flash converters, due to the MAX1171's extremely low 5pF input capacitance and high 300k Ω input impedance. For example, for an input signal of ± 2 Vp-p with an input frequency of 10MHz, the peak output current required for the driving circuit is only 628µA.

Clock Input

The MAX1171 is driven from a single-ended TTL input (CLK). For optimal noise performance, the clock input slew rate should be a minimum of 6ns. Because of this, the use of fast logic is recommended. The clock input duty cycle should be 50% where possible, but performance will not be degraded if kept within the range of 40% to 60%. However, in any case, the clock pulse width (tpwH) must be kept at 300ns maximum to ensure proper operation of the internal track/hold amplifier (Figure 1a). The analog input signal is latched on the rising edge of the CLK.

The clock input must be driven from fast TTL logic ($V_{IH} \le 4.5V$, $t_{RISE} < 6ns$). In the event the clock is driven from a high current source, use a 100Ω resistor (R1, Figure 2) in series to current limit to approximately 45mA.

Digital Outputs

The format of the output data (D0-D11) is straight binary (Table 2). The outputs are latched on the rising edge of CLK with a typical propagation delay of 14ns. There is a one clock cycle latency between CLK and the valid output data (Figure 1a).

The digital outputs' rise times and fall times are not symmetrical. The rise time's typical propagation delay is 14ns, and the typical fall time is 6ns (Figure 4). The nonsymmetrical rise and fall times create approximately 8ns of invalid data.

Table 2. Output Data Information

ANALOG INPUT	OVERRANGE D10	OUTPUT CODE D9-D0
> +2.0V + 1/2LSB	1	11 1111 1111
+2.0V - 1LSB	0	11 1111 1110
0.0V	0	00 0000 0000
-2.0V + 1LSB	0	00 0000 000Ø
< -2.0V	0	00 0000 0000

(Ø indicates the flickering bit between logic 0 and 1).

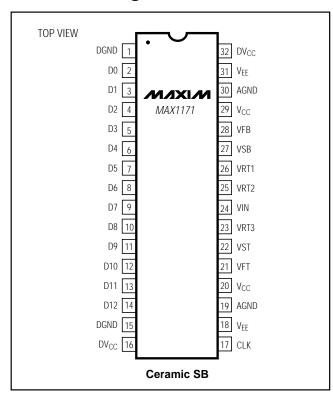
Overrange Output

The overrange output (D12) is an indication that the analog input signal has exceeded the full-scale input voltage by 1LSB. When this condition occurs, the outputs will switch to logic 1s. All other data outputs are unaffected by this operation. This feature makes it possible to include the MAX1171 in higher resolution systems.

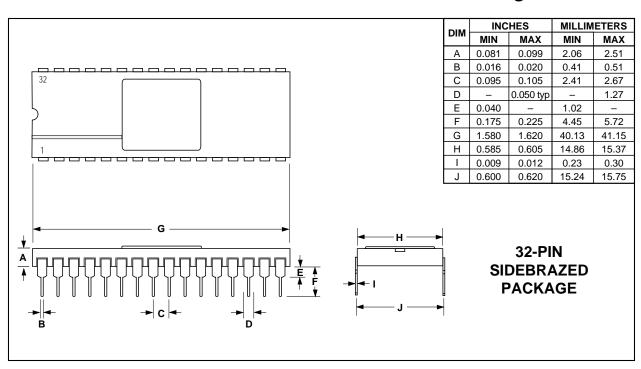
Evaluation Board

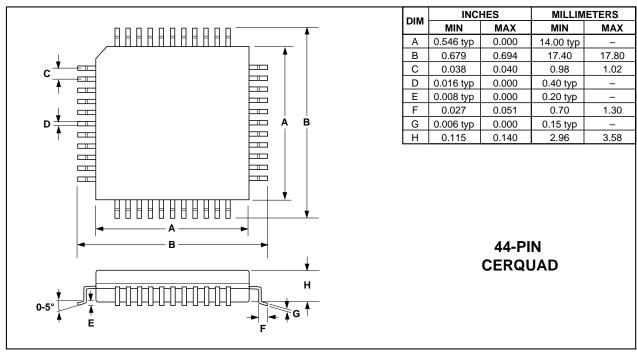
The MAX1170 evaluation kit (EV kit) is available to aid designers in demonstrating the full performance of the MAX1171 (or of the MAX1170/MAX1172). This board includes a reference circuit, clock driver circuit, output data latches, and on-board reconstruction of the digital data. A separate EV kit manual describing the operation of this board is available. Contact the factory for price and availability.

Pin Configurations (continued)



Package Information





Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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